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1	TRADEMARK OFFICE PATENT AND TRADEMARK OFFICE
2	EXAMINER: NGUYEN, THINH T.
3	APPLICANTS: JAMIN LING, ET AL.
4	SERIAL NO.: 09/766,798 FILED: Jan. 22, 2001
5	FILED: Jan. 22, 2001
6 7	FOR: "ELECTROLESS Ni/Pd/Au METALLIZATION) STRUCTURE FOR COPPER INTERCONNECT) SUBSTRATE AND METHOD THEREFOR")
8	I hereby certify that this correspondence is being deposited with the United
9	States Postal Service as first class mail in an envelope addressed to: Commissioner for Patents, Washington, D.C. 20231 on: March 21, 2002 Marvin A. Glazer Name of Registered Rep. March 21, 2002 Signature AMENDMENT
10	Marvin A. Glazer Name of Registered Rep.
11	March 21,2002 = 5
12	Signature U Date
13	<u>AMENDMENT</u>
14 15	Honorable Commissioner for Patents Washington, D.C. 20231
16	Sir:
17	In response to the Office Action mailed on December 5, 2001, please amend the above-
18	identified patent application as follows:
19	In the Claims:
20	Amend claim 1 as follows:
21	1. (Amended) An integrated circuit structure comprising in combination:
22	a. a semiconductor wafer having an upper surface, the semiconductor wafer having a
23	plurality of identical die formed therein, each of the identical die having a plurality of
24	semiconductor devices formed therein upon the surface of the semiconductor wafer;
25	b. a patterned layer of interconnect metal formed upon the upper surface of the
26	semiconductor wafer for electrically interconnecting the plurality of semiconductor devices
27	formed within each such die, said patterned layer of interconnect metal including connection
28	pads for making electrical connection to circuitry external to the semiconductor wafer;